

FLEX PHOTOIMAGE MASK NPR-80/ID60

- Alkaline Developable Photoimagable Solder Mask for Flex PCBs -

Product system

Main resin:

NPR-80 /ID60 (Green color)

Hardener:

HARDENER PF-10 /ID60



370-1, Nibukata-machi, Hachioji-shi, Tokyo Japan 193-0822 Tel. 81-42-652-0216 / Fax. 81-42-652-0218 URL: http://www.nptcorp.com

1. General

FLEX PHOTOIMAGE MASK "NPR-80/ID60" is the flame retarded solder resist with the halogen compound. The features of this product are flame retardancy, excellent reliability and low tackiness. It is alkaline developable two component ink coated the screen printing. It is developed for a high density flexible printed circuit boards (FPCs).

2. Special Features

- UL 94 V-0.
- Low tackiness, the contact exposure is possible.
- **Good** bending resistance, real plane flexible circuit is always expectable.
- **Stable in electroless Ni/Au plating operation, good plating results is always expectable.**
- Excellent characteristic of PCT, HHBT.
- **By** the way of photoimaging, a superior fine line, fine pitch resolution is expectable.

3. Direction to use

i) Preparation	Mix the main resins "NPR-80/ID60" with the specified hardener "PF-10/ID60" by
of the ink	the instructed ratio, and stir thoroughly before use. Hold for at least 30 minutes before
	put into application.
	* Use as supplied, without dilution as possible. Dilution might cause a drop of
	coated-film thickness on the edge of the circuit. Employ the specified thinner
	SOLVENT #8500 for the purpose, if a dilution is absolutely required.

Specifications of the ink

	NPR-80/ ID60	HARDENER PF-10/ ID60
Packaging size	720 g	280 g
Ratio of Main Resins / Hardener	100 g / 39) g
Form	Green - colored paste	Pale brown - colored paste
Flash point (sealed cup, Seta method)	82 deg. C	72 deg. C
Specific Gravity (25 deg. C)	1.2	1.2
Antifoaming agent	Silicon type (Silicon polymer)	

<u> *Same Servical Data Sheet (EN)*</u>

FLEX PHOTOIMAGE MASK NPR-80/ID60

Viscosity of mixture (25 deg. C, Viscotester VT-04, No.2 rotor)	200~240 dPa•s
Thixotropic Index of mixture (25 deg. C, Brookfield HBT)	1.6~2.0
Solid content of mixture (at 130 deg. C for 1hour in a box oven)	about 77 wt%
Shelf life (Store at 25 deg. C)	about 90 days
Pot life (Store at 25 deg. C	about 3 days
Specified thinner for NPR-80 series	Solvent #8500 (made by Nippon Polytech Corp.)

ii) Coating	Screen printing application is recommended as for the coating method. A 100 to					
	150 meshes polyester-based screen is recommended.					
	Thickness of solder mask after final curing is recommended 15 to 25 μm on the					
	circuit. In case the film thickness is thick excessively, the tackiness, flexibility					
	developability might fall off.					
iii) Holding	Hold in a clean area for 10 to 30 minutes at room temperature to antifoam the					
	coating ink.					
iv) Drying	[Recommendable drying conditions is as follows]					
	70 deg. C, 30-60 minutes or 75 deg. C, 30-45 minutes or 80 deg. C, 30minutes					
	* The limitations of drying conditions are at 70 deg. C for 75 minutes, 75 deg. C for					
	60 minutes, 80 deg. C for 45 minutes. Do not exceed the said limitation, which might					
	cause a poor developability of coated-film itself.					
v) Cooling	Hold in a cool area, or use a cooling instrument, to cool down the substrate to the					
	room temperature.					

Ç

vi) Exposure	[Recommendable exposure co	onditions is as follows]			
	_	et ³⁾ on Cu film is recommended for exposure purpose.			
		to 600 mJ/cm^2 at scattered light with 7kw metal halide			
	lamp.				
	Do not be short of exposure energy, which might cause the reliability of cured-film				
	itself. In case of excess exposure energy, the halation might cause.				
	The steps are different by th	e preparation condition of test pieces. The steps were			
	obtained by doing the condition	ons of Clause 14.			
	3) 21steps tablet; Photec 21	step density tablet made by Hitachi Chemical Co., Ltd.			
vii) Holding	Hold in a clean area for 10	to 30 minutes at room temperature to become stable			
	the photosensitivity.				
viii) Developing	[Recommendable developing	conditions is as follows]			
	Solution;	1.0 wt% - Na ₂ CO ₃ aqueous solution			
	Solution temperature;	30 deg. C			
	Spray pressure;	0.1 to 0.2 MPa			
	Developing time;	60 to 90 seconds			
	Do not exceed the stated limitation, which might cause the poor flexibility and the				
	reliability of cured-film itself.				
ix) Rinsing	[Recommendable rinsing con	ditions is as follows]			
	Solution;	City water and ion exchanged water			
	Rinsing process;	1 st step- City wate <u>r</u> , 2 nd step – ion exchanged water			
	Solution temperature;	30 deg. C			
	Spray pressure;	0.1 to 0.2 MPa			
	Rinsing time;	60 to 90 seconds			
	In the case that the rinsing is	not sufficient, the flexibility and reliability of the cured			
	film might fall off. Wash it sufficiently by using city water and ion exchanged water.				
x) Thermal curing	Perform the curing in 150 deg. C for 30 to 60 minutes in a box oven.				
	* Post-cure; Use UV conve	yer, in case of plating			

FLEX PHOTOIMAGE MASK NPR-80/ID60

<u>4. Pot Life</u>						
Time after mix	0.5 hours	1 day	2 days	3 days	4 days	5 days
Viscosity ⁴⁾	210	230	240	240	240	250
(dPa·s, 25 deg. C)	210	230	240	240	240	230
drying conditions	Developability					
80 deg. C- 30 minutes	No residue	No residue	No residue	No residue	No residue	No residue
- 45 minutes	No residue	No residue	No residue	No residue	No residue	No residue
- 60 minutes	No residue	No residue	No residue	No residue	Residue	Residue
- 75 minutes	Residue	Residue	Residue	Residue	Residue	Residue
- 90 minutes	Residue	Residue	Residue	Residue	Residue	Residue

4) 25 deg. C, Viscotester VT-04, No.2 rotor

5. Pre-drying condition vs. Developability

Pre-dry conditions	70deg. C	75deg. C	80deg. C	85deg. C	90deg. C
30 minutes	No residue	No residue	No residue	No residue	Residue
45 minutes	No residue	No residue	No residue	Residue	Residue
60 minutes	No residue	No residue	No residue	Residue	Residue
75 minutes	No residue	No residue	Residue	Residue	Residue
90 minutes	No residue	Residue	Residue	Residue	Residue

<u>6. Developability after coating ⁵⁾</u>					
Pre-dry conditions	Right after coating	1 day	2 days	3 days	
80deg. C- 30 minutes	No residue	No residue	No residue	No residue	
- 45 minutes	No residue	No residue	No residue	Residue	
- 60 minutes	No residue	No residue	Residue	Residue	
- 75 minutes	Residue	Residue	Residue	Residue	
- 90 minutes	Residue	Residue	Residue	Residue	

5) Store in a clean area at room temperature after UV exposure.

7. Physical Properties

Test items		Typical value	Reference data	
Photosensitivity on rolled Cu substrate			8-9	Hitachi 21 step tablet ³⁾
			9 – 10	Stouffer 21 step guide ⁶⁾
			26 - 31	Stouffer 41 step guide ⁷⁾
Resolution (µm) on	roll	ed Cu substrate	40 / 40	Hitachi Photec G2 test pattern ⁸⁾
(Line / Space)			50 / 300	Hitachi Photec No.1 test pattern ⁹⁾
Donail hardnass on	ro11o	d Connor	5H	JIS K 5600, cohesive fracture
Pencil hardness on	lone	u Coppei	2Н	JIS K 5600, plastic deformation
Adhesive strength	strength Cross-cut test		Class 0	JIS K 5600, Tape peeling
on rolled Copper	Ch	ecker flag type	Pass	TM 2.4.28.1 of IPC-TM-650
-	esist	ance on rolled	Pass 2 cycles	RMA flux applied,
Copper				260 deg. C, 5 seconds
Flexibility on PI file	m (K	Lapton 100H)	Pass	Bending at diameter of 0.2mm
Water absorption (%	6)		No data	23 deg. C, 24 H, dipping in H ₂ O
(film thickness; abo	ut 6	0 μm)	No data	85 deg. C, 85 %Rh, 4 H
Contact angle		H ₂ O	80°	JIS R3257 - Sessile drop method
Tg (deg. C)			70	
Before	Tg ((10 to 40 deg. C)	7 x 10 ⁻⁵	TMA method, Tensile mode
	Immediately after Tg (75 to 81 deg. C)		5 x 10 ⁻³	Load-5gf, Rate-5 deg. C/min. Width-3mm, Length-20mm
After Tg (110 to 140 deg. C)		7 x 10 ⁻⁵		
Young's modulus (GPa)		3.2	1.0 mm/minutes	
Tensile strength (M	Pa)		88	10.0 mm/minutes
Breakdown elongation (%)		(%)	2.3	10.0 mm/minutes

3) Hitachi 21 step tablet; Photec 21 step density tablet made by Hitachi Chemical Co., Ltd.

6) Stouffer 21 step guide; Stouffer 21 step sensitivity guide made by Stouffer Graphic Arts Equipment Co.

7) Stouffer 41 step guide; Transparent step wedge 41 steps by Stouffer Graphic Arts Equipment Co.

8) Resolution; Photec Test Pattern No. G2 negative film made by Hitachi Chemical Co., Ltd.

9) Resolution; Photec Test Pattern No. 1 negative film made by Hitachi Chemical Co., Ltd.



8. Flame retardancy

Flame retardancy	Cover-coat; 10µm	UL 94 V-0	Cover-coat / <u>EPD</u> / Cover-coat EPD; ESPANEX SC substrate, 25µm
	Cover-coat; 30µm	UL 94 V-0	PI film only. (Nippon Steel Chemical)

9. Resistance to solvent ¹¹⁾					
Boiling water test on Cu film ;60 minutes		No peel off	Tape peeling test		
Resistance to solvents of	on Cu film				
MEK IPA (2-propanol) Methylene Chloride	;30 minutes ;30 minutes ;10 minutes	No peel off No peel off a slightly swelling	Tape peeling test after dipping at 23 deg. C		
Resistance to acid/base solutions on Cu film					
10%- H ₂ SO ₄ 10%- HCl 5% - NaOH	;30 minutes ;30 minutes ;30 minutes	No peel off No peel off No peel off	Tape peeling test after dipping at 23 deg. C		

11) Test pieces; pattern of cover coat; TM 2.4.28.1 of IPC-TM-650, PI-Cu substrate: Upisel-N (PI/Cu=25/12μm)

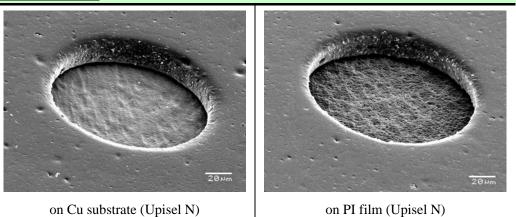
FLEX PHOTOIMAGE MASK NPR-80/ID60

10. Resistance of electrolytic / electroless Ni / Au plating process

Electroless Ni / Au plating		No penetration & No peel off	NPT process ¹²⁾ , Tape peeling test ¹¹⁾
12) C	onditions of electrol	ess Ni / Au plating process (NPT proc	cess)
	Process	Solution	Condition
i)	Acid Cleaner	IPC Clean S-135 ¹³⁾ 200ml/l	40 deg. C- 4 minutes
ii)	Soft etching	(NH ₄) ₂ S ₂ O ₈ 100g/l, H ₂ SO ₄ 10ml/l	23 deg. C- 1 minute
iii)	Smut removal	10% H ₂ SO ₄	23 deg. C- 1 minute
iv)	Pre-dipping	3.5% HCl	23 deg. C- 1 minute
v)	Activation	IPC Accera ¹³⁾ 200ml/l	23 deg. C- 1 minute
vi)	Electroless Ni	IPC Nicoron GM-SD ¹³⁾	80 deg. C- 20 minutes
	plating	Ni content 5.0g/l, pH 4.6	Thickness of Ni plating - about 3µm
vii)	Acid dipping	3.5% HCl	23 deg. C- 1 minute
viii)	Electroless Au	IM-GOLD IB ¹⁴⁾	85 deg. C- 20 minutes
	plating	Au content 2.0g/l, pH 4.8	Thickness of Au plating- about $0.08 \mu m$
ix)	Washing	Ion-exchanged hot water	80 deg. C- 10 minutes
x)	Drying	Box oven	80 deg. C- 3 minutes

13) ICP Clean S-135, ICP Clean 91, ICP Accela, ICP Nicolon GM-SD, and Top Selena; made by Okuno Chemical Industries Co.,Ltd.

14) IM-GOLD IB, Acid strike, Tempereist – EX ; made by Japan Pure Chemical Co.,Ltd.



11. SEM Photograph

FLEX PHOTOIMAGE MASK NPR-80/ID60

4.0		
12.	Electrical	Properties

C

Reliability Test Results			Typical value	Reference data	
Insulation	Line / Space=50 / 50µm		6 x 10 ¹³	- 23 deg. C/55%Rh	
resistance (ohm)	Line / Space=100 / 100µm		8 x 10 ¹³		
Surface Resistance (ohm)			$3 \ge 10^{13}$	TM 2.5.17 of IPC-TM-650	
Volume Resistivity (ohm•cm)			1 x 10 ¹⁶	TM 2.5.17 of IPC-TM-650	
Dielectric Constant (ɛr)		1 MHz	4.11	JIS C6481, 1MHz	
Dielectric Loss Factor (tan δ) 1 M		1 MHz	0.029	JIS C6481, 1MHz	
Dielectric Strength			162 kV/mm	TM 2.6.11 of IPC-TM-650	

13. Reliability Test Results						
HHBT Line / space = 50µm / 50µm (measured resistance condition at test condition)		After 750 hours	No dendrite $(> 10^8 \text{ ohm})$	85 deg. C/85%Rh/100V DC Electrolytic Cu foil		
		After 1000 hours	No dendrite $(> 10^8 \text{ ohm})$			
HHBT Line / space = 100µm / 100µm (measured resistance condition at test condition)		After 750 hours	No dendrite $(> 10^9 \text{ ohm})$	85 deg. C/85%Rh/100V DC Electrolytic Cu foil		
		After 1000 hours	No dendrite $(> 10^9 \text{ ohm})$			
РСТ	on Cu substrate		No peel off	121deg. C/0.2MPa/98h Tape peeling; Checker flag type,		
	on PI film		No peel off	Test pieces; IPC-TM-650 No. 2.4.28.1		
Degradation	in N ₂	5wt%	Loss	307 deg. C	TGA method (40 deg. C/min.)	
Temperature		1st di	ssolution	367 deg. C		
	(dry)	5wt%	Loss	311 deg. C	TGA method (40 deg. C/min.)	
		1st di	ssolution	363 deg. C	-	

	PI: Kapton 100H(25µm), 300H(75µm)	PI; Du Pont-Tray Co., Ltd.	
Substrate:	PI-Cu: Upisel N	PI-Cu; Ube Industries. Ltd.	
Substrate.	(Electrolytic Cu foil; PI/Cu=25/12µm		
	Rolled Cu foil; PI/Cu=25/18µm)		
Thickness of solder mask	About 20 µm		
i) Preparation of the ink	Hold for 30 minutes after mixing	Used a resin mixer, at room	
		temperature	
ii) Coating	100 meshes polyester-based screen	A hand printing	
iii) Holding	23 deg. C- 10 minutes	In the room	
iv) Pre-Drying	80 deg. C - 30 minutes	Box oven	
v) Cooling	23 deg. C - 30 minutes	In the room	
vi) Exposure	500 mJ/cm^2	7kW, Metalhalide lamp, Scattered	
	500 mj/cm	light (ORC Manufacturing Co.)	
vii) Holding	23 deg. C - 10 minutes	In the room	
viii) Developing	1%-Na ₂ CO ₃ aq 30 deg. C	NDT davalaning process	
viii) Developing	- 60 seconds - 0.2 MPa	NPT developing process	
ix) Rinsing:	City water - 30 deg. C	NPT developing process	
inj Kilisilig.	- 60 seconds - 0.2 MPa	TALL developing process	
x) Thermal Curing	150 deg. C - 30 minutes	Box oven	

14. Preparation Conditions of Test Pieces

15. Green Procurement Survey

NPR-80/ID60 contains 0.2 to 0.3wt% of an organic pigment. The organic pigment comes under Copper and Copper Compound (No. 26, Substance Group No. D01) in List A (Appendix 2-2, Level B) based on Guideline for Standardization of Material Declaration (on July 22, 2003 revision) published by Japan Green Procurement Survey Standardization Initiative (JGPSSI;http://home.jeita.or.jp/eps/).

And this product contains 21 to 25wt% (Br content; 9 to 11wt%) of Tetrabromo-bisphenol A compounds as the brominated flame retardant. The brominated flame retardant comes under Tetrabromo-bisphenol A (unspecified, No. 23, Substance Group No. D08) in List A (Appendix 2-2, Level B).

Also, this product is not using the materials/compounds surveyed Chemical Substance except the organic pigment and the flame retardant in the manufacturing process.

16. Special notice

- ✓ <u>Handling</u>
 - The surface hardness of coated film is not hard enough before the thermal curing process. Take it carefully when in handling.
- ✓ Environment of workshop
 - > A clean-room under yellow lamp is required.
 - ➢ Room temperature: 22 to 26 deg. C
 - ▶ Humidity: 50 to 60 % Rh
- ✓ <u>Storage</u>
 - Store at a certain cool and dark area. Temperature in 5 to 25 deg. C is recommendable. Avoid direct sunshine and flame.
 - Hold in room temperature for about 1 day before use, if the storage temperature is under 5 deg. C.
- ✓ <u>Hygienic work Practices</u>
 - > Local exhaust is required to be set up in workshop.
 - > Wear on suitable protective clothing when in operation.
 - > Avoid direct skin contact. Flush with soap and plenty of water thoroughly, if direct contact with skin.
 - > Flush hands, face and body with soap and plenty of water after handling.
- ✓ <u>Inflammability</u>
 - The Principal material "NPR-80/ID60" is the combustible liquid, and the hardener "PF-10/ID60" is the combustible solid. Attention to fire or other sources of ignition.



17. Caution

As to health hazard data, precaution for safe handling/use and others, please refer to the MSDS (Material Safety Data Sheet) of NPR-80/ID60 when in application.

The data mentioned this technical data sheet are based on the results measured NPR-80/ID60 (Green color). In order to get and confirm the sufficient performance, please do the test thoroughly at your end before use.



Nippon Polytech Corp. 370-1, Nibukata-machi, Hachioji-shi, Tokyo Japan 193-0822 Tel. 81-42-652-0216 / Fax. 81-42-652-0218 URL: http://www.nptcorp.com

End of documents